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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS

DATA SHEET

74F74Dual D-type flip-flop

Product specification Supercedes data of 1990 Oct 23 IC15 Data Handbook





Dual D-type flip-flop

74F74

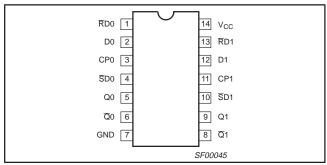
FEATURE

• Industrial temperature range available (-40°C to +85°C)

DESCRIPTION

The 74F74 is a dual positive edge-triggered D-type flip-flop featuring individual data, clock, set, and reset inputs; also true and complementary outputs. Set (\$\overline{S}D\$) and reset (\$\overline{R}D\$) are asynchronous active low inputs and operate independently of the clock input. When set and reset are inactive (high), data at the D input is transferred to the Q and \$\overline{Q}\$ outputs on the low-to-high transition of the clock. Data must be stable just one setup time prior to the low-to-high transition of the clock for predictable operation. Clock triggering occurs at a voltage level and is not directly related to the transition time of the positive-going pulse. Following the hold time interval, data at the D input may be changed without affecting the levels of the output.

PIN CONFIGURATION



TYPE	TYPICAL f _{max}	TYPICAL SUPPLY CURRENT (TOTAL)
74F74	125MHz	11.5mA

ORDERING INFORMATION

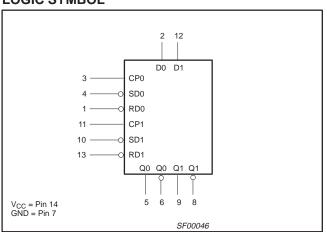
	ORDER		
DESCRIPTION	COMMERCIAL RANGE $V_{CC} = 5V \pm 10\%$, $T_{amb} = 0^{\circ}C \text{ to } +70^{\circ}C$	INDUSTRIAL RANGE V_{CC} = 5V \pm 10%, T_{amb} = -40° C to +85 $^{\circ}$ C	PKG. DWG. #
14-pin plastic DIP	N74F74N	174F74N	SOT27-1
14-pin plastic SO	N74F74D	I74F74D	SOT108-1

INPUT AND OUTPUT LOADING AND FAN OUT TABLE

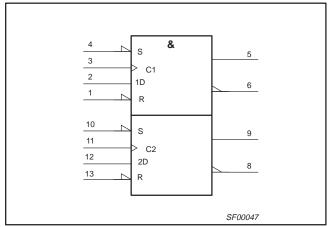
PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
D0, D1	Data inputs	1.0/1.0	20μA/0.6mA
CP0, CP1	Clock inputs (active rising edge)	1.0/1.0	20μA/0.6mA
SD0, SD1	Set inputs (active low)	1.0/3.0	20μA/1.8mA
RD0, RD1	Reset inputs (active low)	1.0/3.0	20μA/1.8mA
Q0, Q1, \overline{Q}0, \overline{Q}1	Data outputs	50/33	1.0mA/20mA

NOTE: One (1.0) FAST unit load is defined as: 20μA in the high state and 0.6mA in the low state.

LOGIC SYMBOL



IEC/IEEE SYMBOL

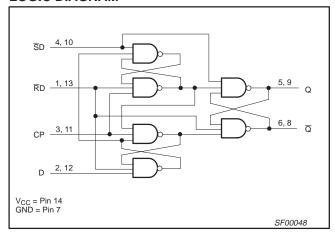


Philips Semiconductors Product specification

Dual D-type flip-flop

74F74

LOGIC DIAGRAM



FUNCTION TABLE

	INP	JTS		OUT	PUTS	OPERATING
SD	RD	СР	D	Q	Q	MODE
L	Н	Х	Х	Н	L	Asynchronous set
Н	L	Х	Х	L	Н	Asynchronous reset
L	L	Х	Х	Н	Н	Undetermined*
Н	Н	1	h	Н	L	Load "1"
Н	Н	↑	I	L	Н	Load "0"
Н	Н	1	Х	NC	NC	Hold

NOTES:

H = High voltage level

= High voltage level one setup time prior to low-to-high clock transition

Low voltage level

= Low voltage level one setup time prior to low-to-high clock transition

NC= No change from the previous setup

= Don't care

= Low-to-high clock transition

 Not low-to-high clock transition
 This setup is unstable and will change when either set or reset return to the high level.

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V _{CC}	Supply voltage		-0.5 to +7.0	V
V _{IN}	Input voltage		-0.5 to +7.0	V
I _{IN}	Input current		-30 to +5	mA
V _{OUT}	Voltage applied to output in high output state		–0.5 to V _{CC}	V
I _{OUT}	Current applied to output in low output state		40	mA
_		Commercial range	0 to +70	°C
T _{amb}	Operating free air temperature range	-40 to +85	°C	
T _{stg}	Storage temperature range	-65 to +150	°C	

RECOMMENDED OPERATING CONDITIONS

CVMDOL	DADAMETER					
SYMBOL	PARAMETER	MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage	4.5	5.0	5.5	V	
V _{IH}	High-level input voltage		2.0			V
V _{IL}	Low-level input voltage			0.8	V	
I _{lk}	Input clamp current				-18	mA
I _{OH}	High-level output current				-1	mA
I _{OL}	Low-level output current			20	mA	
т.	Operating free air temperature range	Commercial range	0		+70	°C
lamb	Operating free air temperature range	Industrial range	-40		+85	°C

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

CYMPOL	PARAMET	FD	TEST CONDITION	ONC1			LIMITS		UNIT
SYMBOL	PARAMETER		TEST CONDITION	TEST CONDITIONS					ONIT
V	V _{OH} High-level output voltage		$V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN$	I _{OH} = MAX	±10%V _{CC}	2.5			V
VOH			$V_{CC} = V_{MIN}, V_{CC} = V_{MIN}, V_{CC} = V_{MIN}$	IOH = INIAX	±5%V _{CC}	2.7	3.4		V
V	Low-level output voltage		$V_{CC} = MIN, V_{II} = MAX, V_{IH} = MIN$	1 - MAY	±10%V _{CC}		0.30	0.50	V
V _{OL}			V _{CC} = Willy, V _{IL} = WAX, V _{IH} = Willy	I _{OL} = MAX	±5%V _{CC}		0.30	0.50	V
V _{IK}	Input clamp voltage		$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.2	V		
II	Input current at max voltage	imum input	$V_{CC} = MAX, V_I = 7.0V$			100	μΑ		
I _{IH}	High-level input curr	ent	$V_{CC} = MAX, V_I = 2.7V$			20	μΑ		
	Low-level input	Dn, CPn	$V_{CC} = MAX, V_I = 0.5V$					-0.6	mA
l IIL	current SDn, RDn		$V_{CC} = MAX, V_I = 0.5V$			-1.8	mA		
Ios	Short-circuit output current ³		$V_{CC} = MAX$	-60		-150	mA		
Icc	Supply current (tota	l) ⁴	V _{CC} = MAX				11.5	16	mA

NOTES:

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.
- All typical values are at $V_{CC} = 5V$, $T_{amb} = 25^{\circ}C$. Not more than one output should be shorted at a time. For testing I_{OS} , the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.
- Measure I_{CC} with the clock input grounded and all outputs open, then with Q and \overline{Q} outputs high in turn.

AC ELECTRICAL CHARACTERISTICS

				LIMITS							
SYMBOL	PARAMETER	TEST CONDITION	$V_{CC} = +5.0V$ $T_{amb} = +25^{\circ}C$ $C_{L} = 50pF, R_{L} = 500\Omega$			$T_{amb} = 0^{\circ}C$	0V ± 10% C to +70°C R _L = 500Ω	$V_{CC} = +5.$ $T_{amb} = -40^{\circ}$ $C_{L} = 50pF$	UNIT		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
f _{max}	Maximum clock frequency	Waveform 1	100	125		100		90		MHz	
t _{PLH} t _{PHL}	Propagation delay CPn to Qn or Qn	Waveform 1	3.8 4.4	5.3 6.2	6.8 8.0	3.8 4.4	7.8 9.2	3.8 4.4	8.5 9.2	ns	
t _{PLH} t _{PHL}	Propagation delay SDn, RDn to Qn or Qn	Waveform 2	3.2 3.5	4.6 7.0	6.1 9.0	3.2 3.5	7.1 10.5	3.2 2.5	7.5 10.5	ns	

AC SETUP REQUIREMENTS

				LIMITS							
SYMBOL	PARAMETER	TEST CONDITION	V_{CC} = +5.0V T_{amb} = +25°C C_L = 50pF, R_L = 500 Ω			$T_{amb} = 0^{\circ}C$	0V ± 10% C to +70°C R _L = 500Ω	$V_{CC} = +5.$ $T_{amb} = -40^{\circ}$ $C_{L} = 50pF$	UNIT		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
t _{su} (H) t _{su} (L)	Setup time, high or low Dn to CPn	Waveform 1	2.0 3.0			2.0 3.0		2.0 3.0		ns	
t _h (H) t _h (L)	Hold time, high or low Dn to CPn	Waveform 1	1.0 1.0			1.0 1.0		1.0 1.0		ns	
t _w (H) t _w (L)	CPn pulse width, high or low	Waveform 1	4.0 5.0			4.0 5.0		4.0 5.0		ns	
t _w (L)	SDn, RDn pulse width, low	Waveform 2	4.0			4.0		4.0		ns	
t _{rec}	Recovery time SDn, RDn to CPn	Waveform 3	2.0			2.0		2.0		ns	

Product specification Philips Semiconductors

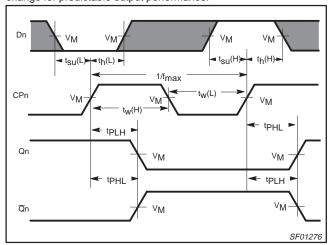
Dual D-type flip-flop

74F74

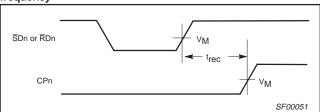
AC WAVEFORMS

For all waveforms, $V_M = 1.5V$.

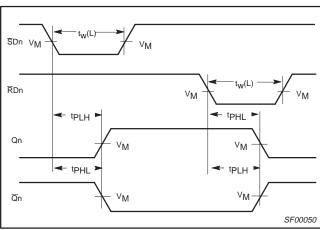
The shaded areas indicate when the input is permitted to change for predictable output performance.



Waveform 1. Propagation delay for data to output, data setup time and hold times, and clock width, and maximum clock frequency

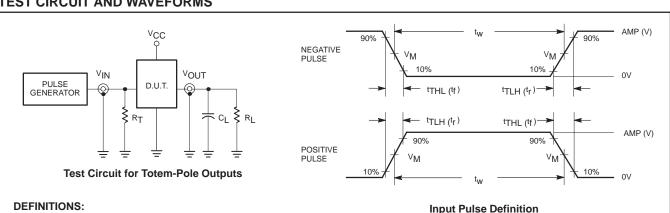


Recovery time for set or reset to clock Waveform 3.



Propagation delay for set and reset to output, set and reset pulse width

TEST CIRCUIT AND WAVEFORMS



R_L = Load resistor;

see AC ELECTRICAL CHARACTERISTICS for value.

Load capacitance includes jig and probe capacitance; see AC ELECTRICAL CHARACTERISTICS for value.

Termination resistance should be equal to $Z_{\mbox{\scriptsize OUT}}$ of pulse generators.

Input Pulse Definition

family	INP	INPUT PULSE REQUIREMENTS									
	amplitude	V _M	rep. rate	t _{TLH}	t _{THL}						
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns					

SF00006

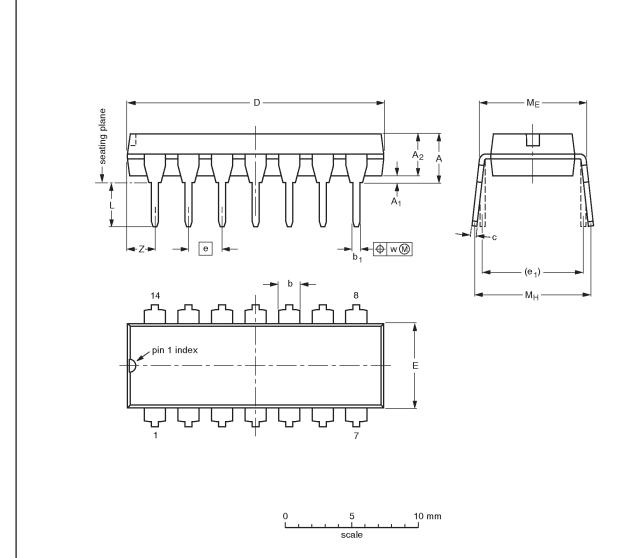
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Dual D-type flip-flop

74F74

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11	

1996 Mar 12 6

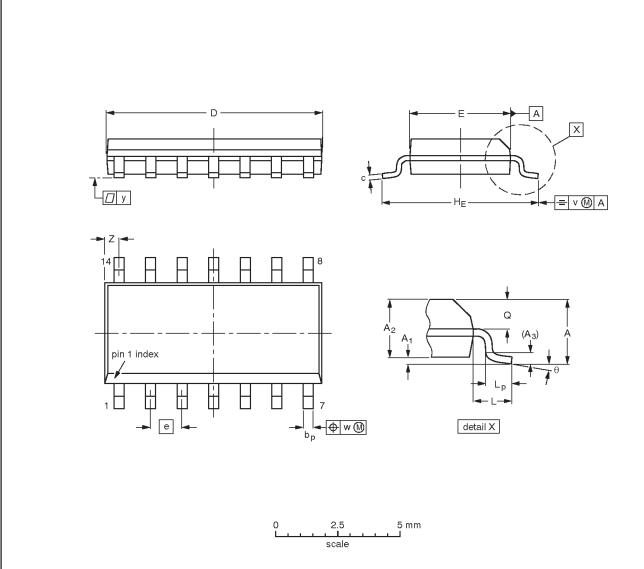
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Dual D-type flip-flop

74F74

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	o°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06S	MS-012AB				95-01-23 97-05-22

1996 Mar 12 7

Dual D-type flip-flop

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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